

P-Channel 60-V (D-S) MOSFET

PRODUCT SUMMARY

V _{DS} (V)	R _{DS(on)} (mΩ)(Typ.)	I _D (A) ^a	Q _g (Typ.)
-60	11 at V _{GS} = - 10 V	-82	62 nC
	13 at V _{GS} = - 4.5 V		

FEATURES

- DT-Trench Power MOSFET
- 100 % R_g and UIS Tested

APPLICATIONS

- Notebook
- Load Switch

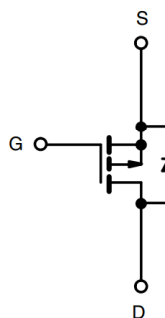


RoHS
COMPLIANT

TO-263 Pin Configuration



Top View



P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise noted)

PARAMETER	SYMBOL	Limit	UNIT
Drain-Source Voltage	V _{DS}	-60	V
Gate-Source Voltage	V _{GS}	±20	
Continuous Drain Current (T _J = 175 °C) ^a	T _A = 25 °C	-82	A
	T _A = 100 °C	-58	
Pulsed Drain Current	I _{DM}	-328	
Continuous Source Current (Diode Conduction) ^a	I _S	-82	
Avalanche Current	I _{AS}	-75	
Single Pulse Avalanche Energy	E _{AS}	722	mJ
Maximum Power Dissipation ^a	T _A = 25 °C	150	W
	T _A = 100 °C	75	
Operating Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +175	°C

THERMAL RESISTANCE RATINGS

PARAMETER	SYMBOL	MAXIMUM	UNIT
Maximum Junction-to-Case (Drain) ^b	R _{thJC}	1	°C/W

Notes:

a. Based on T_C = 25 °C.

b. Surface mounted on 1" x 1" FR4 board.

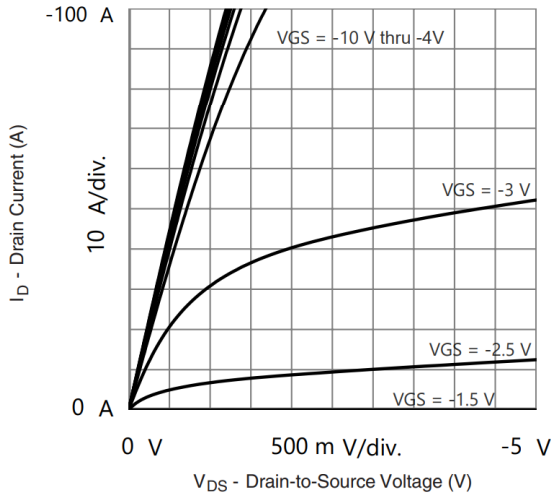
SPECIFICATIONS ($T_J = 25\text{ }^\circ\text{C}$, unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static						
Drain-Source Breakdown Voltage	V_{DS}	$V_{GS} = 0\text{ V}, I_D = -250\text{ }\mu\text{A}$	-60	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\text{ }\mu\text{A}$	-1	-	-3	
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0\text{ V}, V_{GS} = \pm 20\text{ V}$	-	-	± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -60\text{ V}, V_{GS} = 0\text{ V}$	-	-	-1	μA
On-State Drain Current ^a	$I_{D(on)}$	$V_{DS} \geq -10\text{ V}, V_{GS} = -10\text{ V}$	-82	-	-	A
Drain-Source On-State Resistance ^a	$R_{DS(on)}$	$V_{GS} = -10\text{ V}, I_D = -20\text{ A}$	-	11	13	m Ω
		$V_{GS} = -4.5\text{ V}, I_D = -20\text{ A}$	-	13	16	m Ω
Forward Transconductance ^a	g_{fs}	$V_{DS} = -5\text{ V}, I_D = -20\text{ A}$	-	25	-	S
Dynamic ^b						
Input Capacitance	C_{iss}	$V_{GS} = 0\text{ V}, V_{DS} = -30\text{ V}, f = 1\text{ MHz}$	-	4760	-	pF
Output Capacitance	C_{oss}		-	354	-	
Reverse Transfer Capacitance	C_{rss}		-	276	-	
Total Gate Charge ^c	Q_g	$V_{DS} = -30\text{ V}, V_{GS} = -10\text{ V}, I_D = -20\text{ A}$	-	62	-	nC
Gate-Source Charge ^c	Q_{gs}		-	9	-	
Gate-Drain Charge ^c	Q_{gd}		-	17	-	
Gate Resistance	R_g	$f = 1\text{ MHz}$	-	4	-	Ω
Turn-On Delay Time ^c	$t_{d(on)}$	$V_{DD} = -30\text{ V}, R_L = 1.5\Omega$ $I_D = -20\text{ A}, V_{GEN} = -10\text{ V}, R_g = 3\Omega$	-	18	-	ns
Rise Time ^c	t_r		-	20	-	
Turn-Off Delay Time ^c	$t_{d(off)}$		-	55	-	
Fall Time ^c	t_f		-	35	-	
Drain-Source Body Diode Ratings and Characteristics ^b ($T_C = 25\text{ }^\circ\text{C}$)						
Continuous Source Current	I_S	$T_C = 25\text{ }^\circ\text{C}$	-	-	-82	A
Pulsed Source Current	I_{SM}		-	-	-328	A
Forward Voltage ^a	V_{SD}	$I_F = -20\text{ A}, V_{GS} = 0\text{ V}$	-	-	-1.2	V
Reverse Recovery Time	t_{rr}	$I_F = -20\text{ A}, di/dt = -100\text{ A}/\mu\text{s}$	-	49	-	ns
Reverse Recovery Charge	Q_{rr}		-	71	-	nC

Notes

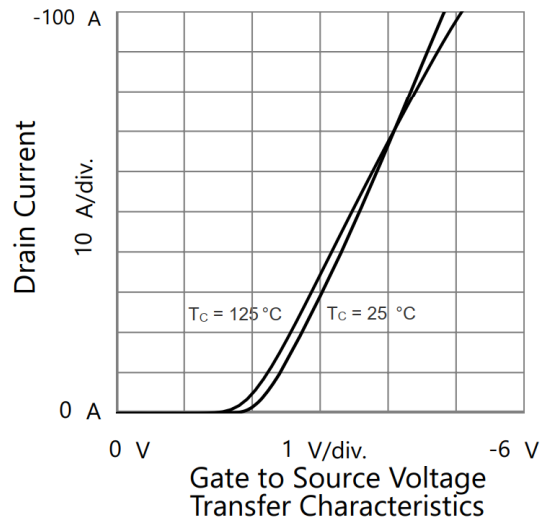
- Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$.
- Guaranteed by design, not subject to production testing.
- Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

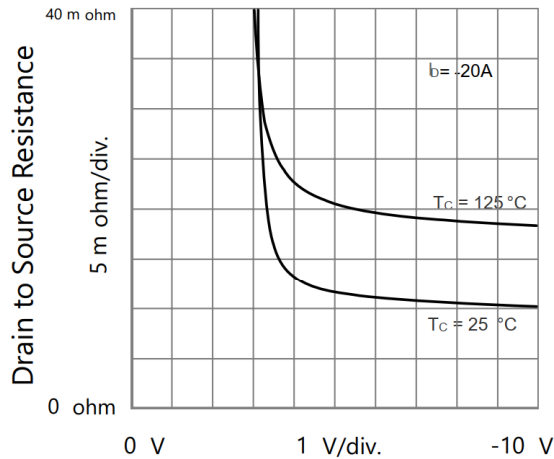
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



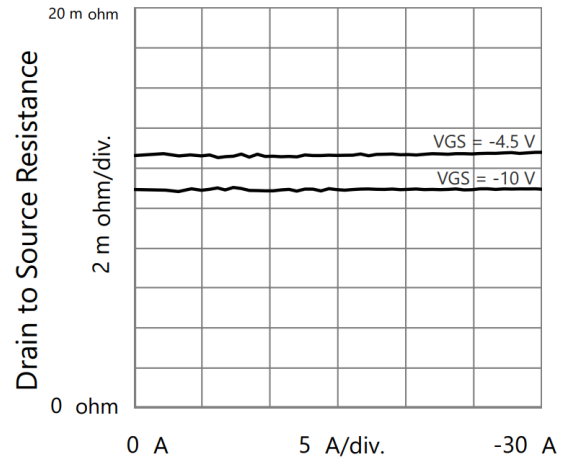
Output Characteristics



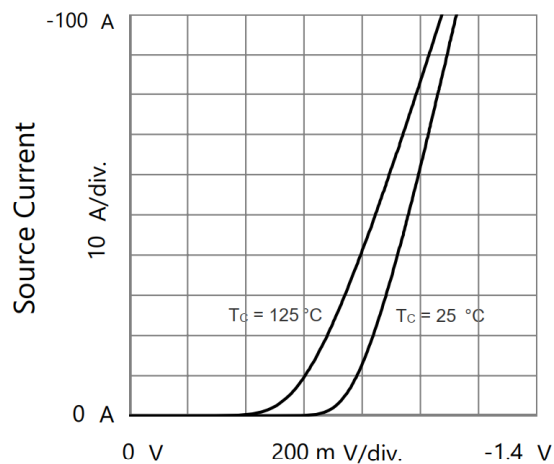
Transfer Characteristics



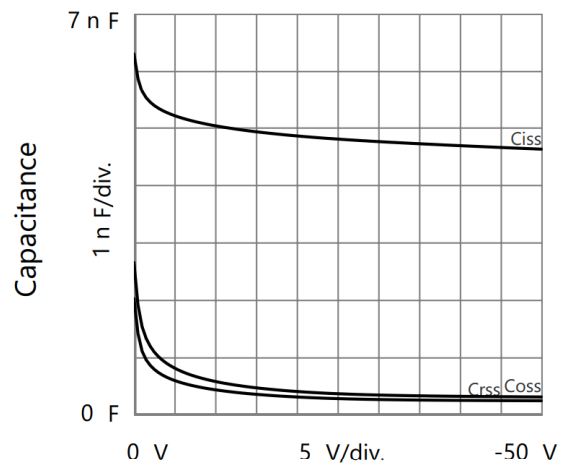
Gate to Source Voltage
Drain to Source Resistance vs. Gate to Source Voltage



Drain Current
Drain to Source Resistance vs. Drain Current

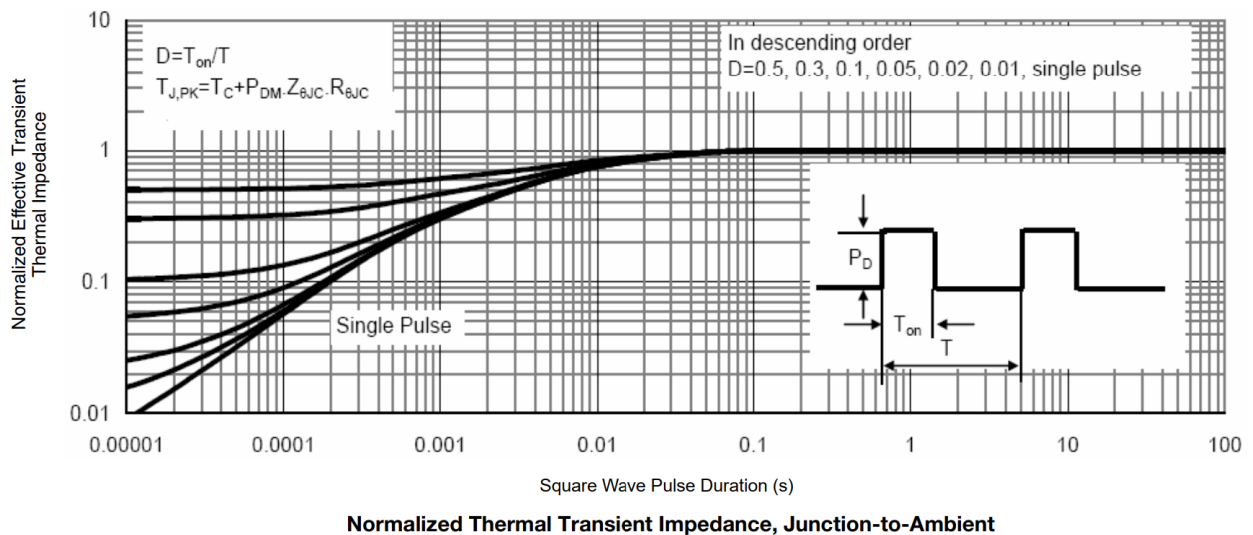
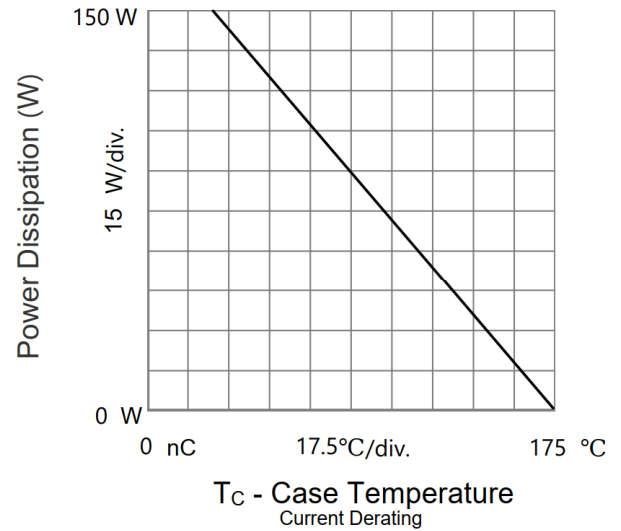
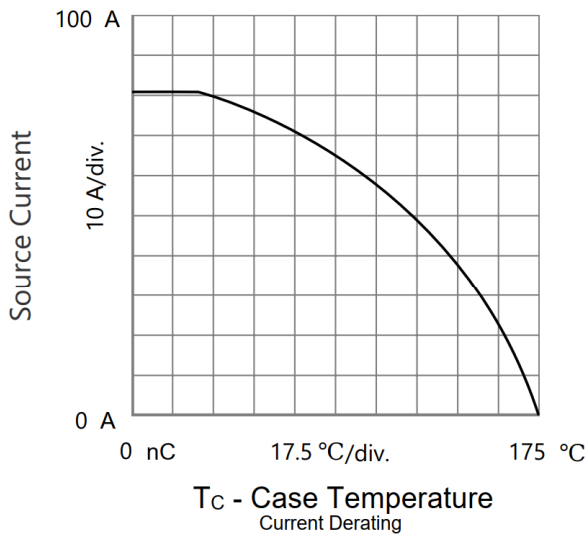
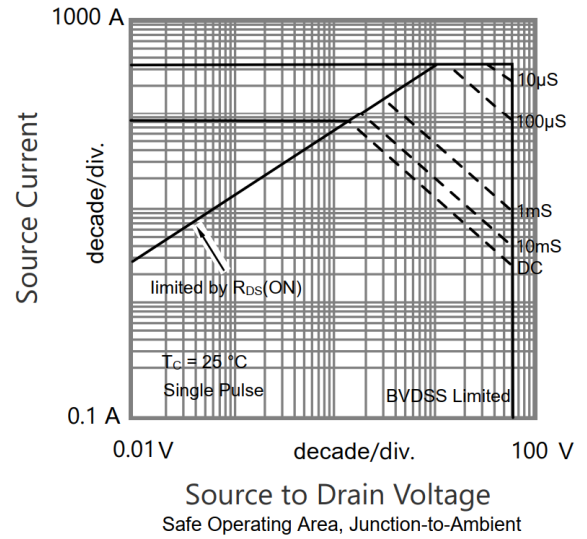
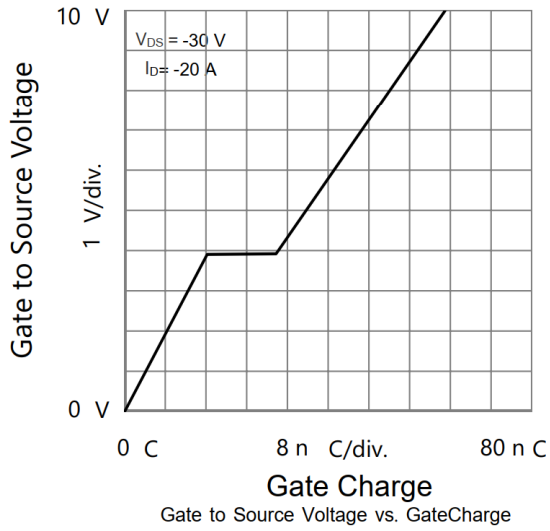


Body Diode Forward Characteristics

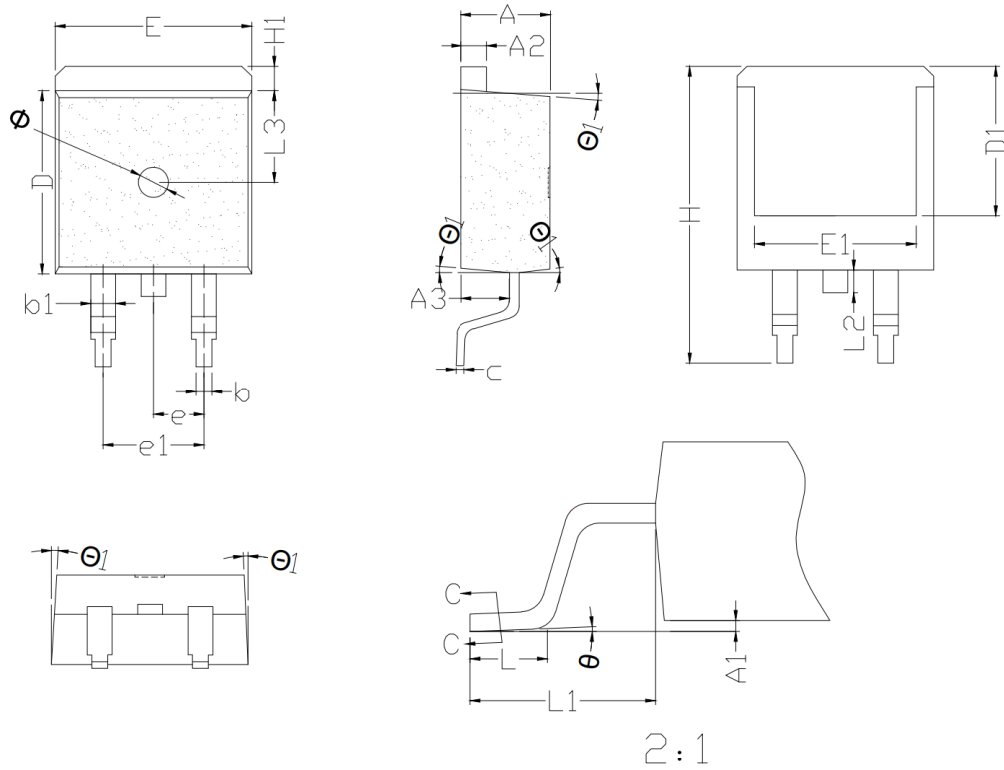


Capacitances
Drain to Source Voltage Capacitances

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



TO-263 PACKAGE OUTLINE



COMMON DIMENSIONS
(UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	TYP	MAX	SYMBOL	MIN	TYP	MAX
A	4.10	4.50	4.80	e	2.35	2.54	2.75
A1	0.00	0.10	0.30	e1	5.08REF		
A2	1.10	1.30	1.50	H	14.50	15.15	16.00
A3	2.15	2.50	3.10	H1	1.00	1.28	1.75
b	0.60	0.80	1.05	L	1.80	2.23	2.90
b1	1.05	1.33	1.50	L1	4.30	4.75	5.50
c	0.33	0.50	0.66	L2	1.00	1.30	1.85
D	8.40	9.20	9.60	L3	0.90	4.65	9.00
D1	7.50REF			phi	0°	2°	5°
E	9.60	10.02	10.80	phi1	2°	-	7°
E1	7.60	9.88	10.30	Phi	1.5BSC		

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